

The clean copy of the paragraph is:

The invention is in the field of the plastic circuitry and components being employed in

Q1
cont'd. electronic technology, and in particular to devices containing N,N" 3,4,9,10 perylene

tetracarboxylic acid diimide semiconductor materials in such devices as organic thin film
transistors.

Page 3 in the paragraph beginning on line 6

In line 6 change "The each" to -Each- and in line 8 change" N,N" 3,4,9,10 perylene

tetracarboxylic acid diimide" to- N,N"-di(n-1H,1H-perfluooctyl)perylene 3,4,9,10- tetracarboxylic

acid diimide- by erasing the cross hatched //The//~~each~~// and replacing with the underlined Each ,

and erasing the cross hatched// ~~of the invention//N,N"3,4,9,10 perylene tetracarboxylic acid~~//

~~diimide//~~ and inserting the underlined N,N"-di(n-1H, 1H-perfluorooctyl) perylene 3,4,9,10-

tetracarboxylic acid diimide.

The clean copy is:

Q2 An organic TFT is shown in Figs 1 & 2. Each TFT contains a source electrode 10, a drain